NE5534, NE5534A, SA5534. SA5534A LOW-NOISE OPERATIONAL AMPLIFIERS

SLOS070C - JULY 1979 - REVISED SEPTEMBER 2004

- Equivalent Input Noise Voltage . . .
 3.5 nV/√Hz Typ
- Unity-Gain Bandwidth . . . 10 MHz Typ
- Common-Mode Rejection Ratio . . .
 100 dB Typ
- High DC Voltage Gain . . . 100 V/mV Typ
- Peak-to-Peak Output Voltage Swing
 32 V Typ With V_{CC±} = ±18 V and R_L = 600 Ω
- High Slew Rate . . . 13 V/μs Typ
- Wide Supply-Voltage Range ±3 V to ±20 V
- Low Harmonic Distortion
- Offset Nulling Capability
- External Compensation Capability

description/ordering information

The NE5534A, NE5534A, SA5534A, and SA5534A are high-performance operational amplifiers combining excellent dc and ac characteristics. Some of the features include very low noise, high output-drive capability, high unity-gain and maximum-output-swing bandwidths, low distortion, and high slew rate.

These operational amplifiers are compensated internally for a gain equal to or greater than three. Optimization of the frequency response for various applications can be obtained by use of an external compensation capacitor between COMP and COMP/BAL. The devices feature input-protection diodes, output short-circuit protection, and offset-voltage nulling capability with use of the BALANCE and COMP/BAL pins (see the application circuit diagram).

For the NE5534A and SA5534A, a maximum limit is specified for the equivalent input noise voltage.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



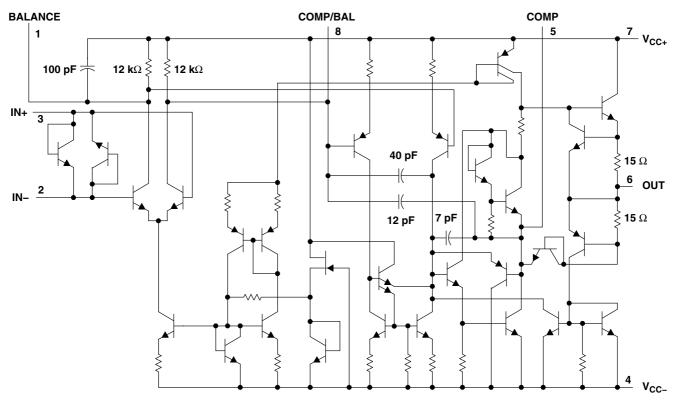
description/ordering information (continued)

ORDERING INFORMATION

T _A	V _{IO} max AT 25°C	PACKA	GE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
		DDID (D)	Tube of 50	NE5534P	NE5534P
		PDIP (P)	Tube of 50	NE5534AP	NE5534AP
			Tube of 75	NE5534D	NECCO4
0°C to 70°C	4 mV	COIC (D)	Reel of 2500	NE5534DR	NE5534
		SOIC (D)	Tube of 75	NE5534AD	55044
			Reel of 2500	NE5534ADR	5534A
		SOP (PS)	Reel of 2000	NE5534PSR	N5534
		DDID (D)	Tube of 50	SA5534P	SA5534P
		PDIP (P)	Tube of 50	SA5534AP	SA5534AP
			Tube of 75	SA5534D	045504
4000 4 0500	4 14	SOIC (D)	Reel of 2500	SA5534DR	SA5534
-40°C to 85°C	4 mV	SOIC (D)	Tube of 75	SA5534AD	CAFFOAA
			Reel of 2500	SA5534ADR	SA5534A
		SOB (BS)	Tube of 80	SA553APS	SA5534
		SOP (PS)	Reel of 2000	SA553APSR	3A3334

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

schematic

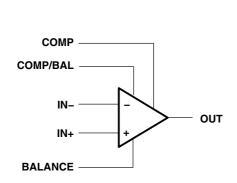


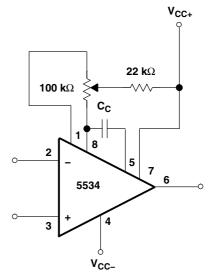
All component values shown are nominal.



symbol

application circuit





Frequency Compensation and Offset-Voltage Nulling Circuit

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage: V _{CC+} (see Note 1)		22 V
V _{CC} - (see Note 1)		–22 V
Input voltage either input (see Notes 1 and 2)		V _{CC+}
Input current (see Note 3)		
Duration of output short circuit (see Note 4)		Unlimited
Package thermal impedance, θ_{JA} (see Notes 5 and 6):	D package	97°C/W
	P package	85°C/W
	PS package	95°C/W
Operating virtual junction temperature, T _J		150°C
Storage temperature range, T _{stq}		-65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-}
 - 2. The magnitude of the input voltage must never exceed the magnitude of the supply voltage.
 - 3. Excessive current will flow if a differential input voltage in excess of approximately 0.6 V is applied between the inputs, unless some limiting resistance is used.
 - 4. The output may be shorted to ground or to either power supply. Temperature and/or supply voltages must be limited to ensure the maximum dissipation rating is not exceeded.
 - 5. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
 - 6. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions

			MIN	MAX	UNIT
V _{CC+}	Supply voltage		5	15	V
V _{CC} -	Supply voltage		-5	-15	V
_	Operating free six temperature renge	NE5534, NE5534A	0	70	°C
T _A	Operating free-air temperature range	-40	85	°C	



NE5534, NE5534A, SA5534. SA5534A LOW-NOISE OPERATIONAL AMPLIFIERS

SLOS070C - JULY 1979 - REVISED SEPTEMBER 2004

electrical characteristics, $V_{CC}\pm$ = ±15 V, T_{A} = $25^{\circ}C$ (unless otherwise noted)

	PARAMETER	TEST CONDI	MIN	TYP	MAX	UNIT		
,,	lament offerst violations	$V_{O} = 0$,	T _A = 25°C		0.5	4		
V_{IO}	Input offset voltage	$R_S = 50 \Omega$	T _A = Full range			5	mV	
	land offer at a consent	V 0	T _A = 25°C		20	300	4	
I _{IO}	Input offset current	$V_O = 0$	$T_A = Full range$			400	nA	
	Innut bice correct	V 0	T _A = 25°C		500	1500	nA	
I _{IB}	Input bias current	$V_O = 0$	$T_A = Full range$			2000	ΠA	
V _{ICR}	Common-mode input voltage range			±12	±13		٧	
,	Marian and the most subset with an arrive	D > 000 O	$V_{CC\pm} = \pm 15 \text{ V}$	24	26		٧	
V _{O(PP)}	Maximum peak-to-peak output voltage swing	$R_L \ge 600 \Omega$	$V_{CC\pm} = \pm 18 \text{ V}$	30	32		٧	
	Lavas aignal differential vallege appelification	$V_0 = \pm 10 \text{ V},$	T _A = 25°C	25	100		MacM	
A_{VD}	Large-signal differential voltage amplification	$R_L \ge 600 \Omega$	$T_A = Full range$	15			V/mV	
	Consultational differential valleges are differential	4 40 141-	C _C = 0		6		MacM	
A _{vd}	Small-signal differential voltage amplification	f = 10 kHz	$C_C = 22 pF$		2.2		V/mV	
		V 140 V	C _C = 0		200			
B _{OM}	Maximum-output-swing bandwidth	$V_O = \pm 10 \text{ V}$	$C_C = 22 pF$		95		kHz	
БОМ	Maximum output swing bandwidth	$V_{CC\pm} = \pm 18 \text{ V},$ $R_L \ge 600 \Omega,$	$V_O = \pm 14 \text{ V},$ $C_C = 22 \text{ pF}$		70		KHZ	
B ₁	Unity-gain bandwidth	$C_C = 22 \text{ pF},$	C _L = 100 pF		10		MHz	
r _i	Input resistance			30	100		kΩ	
z _o	Output impedance	$A_{VD} = 30 \text{ dB},$ $C_{C} = 22 \text{ pF},$	$R_L \ge 600 \Omega$, $f = 10 \text{ kHz}$		0.3		Ω	
CMRR	Common-mode rejection ratio	$V_O = 0$, $R_S = 50 \Omega$	$V_{IC} = V_{ICR}min^{-1}$	70	100		dB	
k _{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC}/\Delta V_{IO}$)	$V_{CC+} = \pm 9 \text{ V to } \pm 15 \text{ V},$ $V_{O} = 0$	$R_S = 50 \Omega$,	80	100		dB	
Ios	Output short-circuit current				38		mA	
I _{CC}	Supply current	V _O = 0, No load	T _A = 25°C	_	4	8	mA	

[†] All characteristics are measured under open-loop conditions with zero common-mode input voltage, unless otherwise specified. For NE5534 and NE5534A, full range is 0°C to 70°C. For SA5534 and SA5534A, full range is –40°C to 85°C.

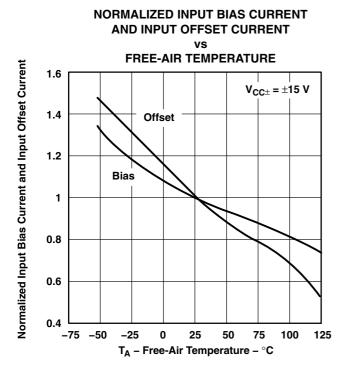
NE5534, NE5534A, SA5534. SA5534A LOW-NOISE OPERATIONAL AMPLIFIERS

SLOS070C - JULY 1979 - REVISED SEPTEMBER 2004

operating characteristics, $V_{CC}\,\pm$ = ±15 V, T_{A} = $25^{\circ}C$

PARAMETER		TEST (CONDITIONS	NE5534, SA5534	NE5534A, SA5534A			UNIT	
				TYP	MIN	TYP	MAX		
CD	Classificate	C _C = 0		13		13		Mora	
SR	Slew rate	C _C = 22 pF		6		6		V/μs	
	Rise time		$A_{VD} = 1$, $C_C = 22 pF$	20		20		ns	
	Overshoot factor	$R_L = 600 \Omega,$ $C_L = 100 pF$	OC = 22 br	20		20		%	
t _r	Rise time	$V_1 = 50 \text{ mV},$	$A_{VD} = 1$, $C_C = 47 \text{ pF}$	50		50		ns	
	Overshoot factor	$R_L = 600 \Omega,$ $C_L = 500 pF$	OC = 47 PF	35		35		%	
v	Cavinglant input paige valtage	f = 30 Hz		7		5.5	7	\/\	
V _n	Equivalent input noise voltage	f = 1 kHz		4		3.5	4.5	nV/√Hz	
	Fundament in the control of the cont	f = 30 Hz f = 1 kHz		2.5		1.5		- A / /III	
In	Equivalent input noise current			0.6		0.4		pA/√ Hz	
F	Average noise figure	$R_S = 5 k\Omega$	f = 10 Hz to 20 kHz			0.9		dB	

TYPICAL CHARACTERISTICS[†]



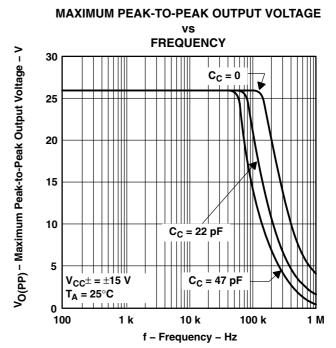


Figure 2

Figure 1

LARGE-SIGNAL

DIFFERENTIAL VOLTAGE AMPLIFICATION

vs **FREQUENCY**

 $C_C = 22 pF$

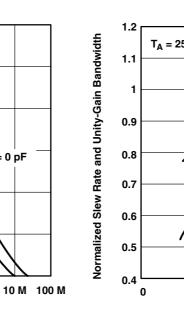
10 k 100 k

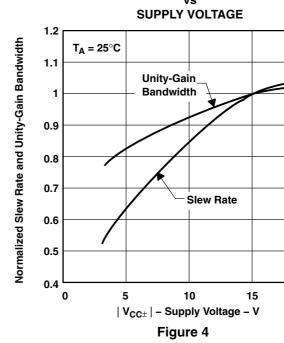
f - Frequency - Hz

Figure 3

1 M







20

 $C_C = 0 pF$



10⁶

10⁵

10⁴

10³

10²

10

10

100

1 k

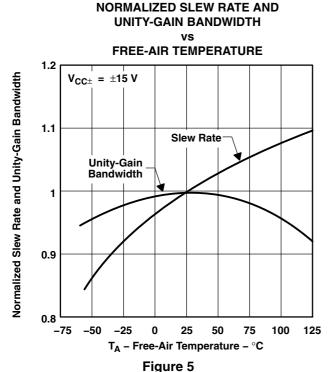
 $V_{CC\pm} = \pm 15 \text{ V}$

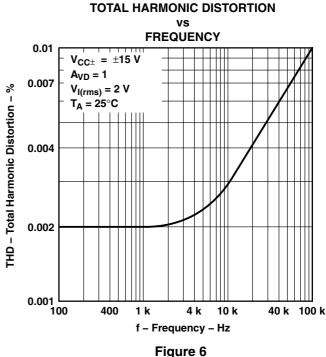
T_A = 25°C

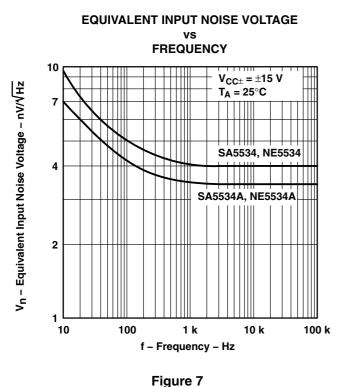
Avp - Differential Voltage Amplification - V/mV

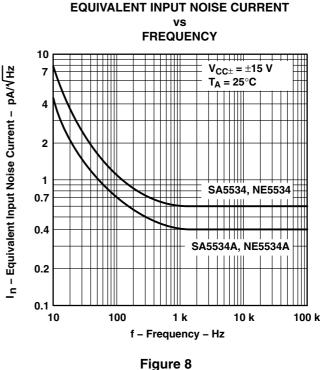
[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS[†]









[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

TOTAL EQUIVALENT INPUT NOISE VOLTAGE vs SOURCE RESISTANCE

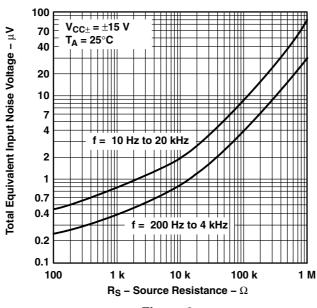


Figure 9



20-Aug-2011

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
NE5534AD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
NE5534ADE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
NE5534ADG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
NE5534ADR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
NE5534ADRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
NE5534ADRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
NE5534AJG	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI	
NE5534AP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
NE5534APE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
NE5534D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
NE5534DE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
NE5534DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
NE5534DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
NE5534DRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
NE5534DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
NE5534IP	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI	
NE5534P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
NE5534PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SA5534AD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	





20-Aug-2011

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
SA5534ADE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SA5534ADG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SA5534ADR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SA5534ADRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SA5534ADRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SA5534AP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SA5534APE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SA5534D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SA5534DE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SA5534DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SA5534DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SA5534DRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SA5534DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SA5534P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SA5534PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SA5534PSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SA5534PSRE4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SA5534PSRG4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.



PACKAGE OPTION ADDENDUM

20-Aug-2011

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

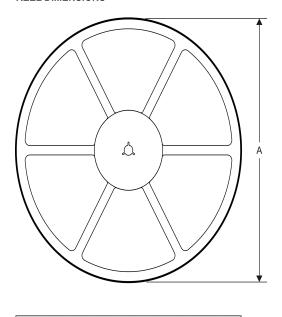
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

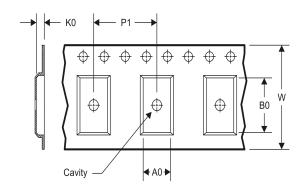
www.ti.com 14-Jul-2012

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

"All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
NE5534ADR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
NE5534DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SA5534ADR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SA5534DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SA5534PSR	SO	PS	8	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1

www.ti.com 14-Jul-2012

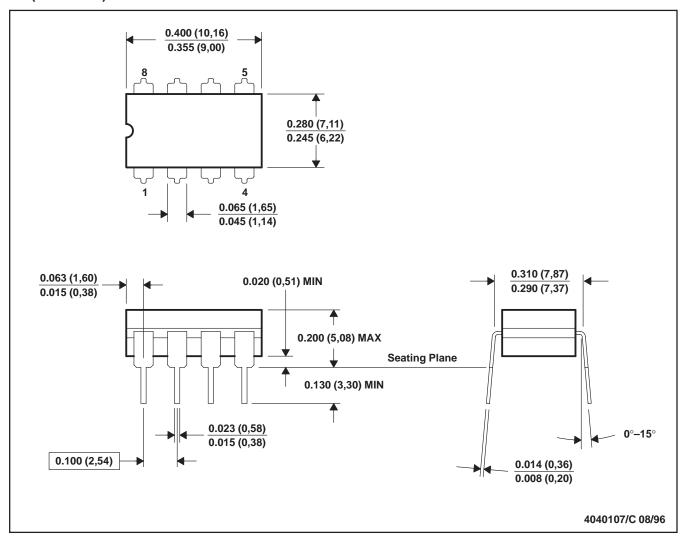


*All dimensions are nominal

7 til diffictiolotio are florifital							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
NE5534ADR	SOIC	D	8	2500	340.5	338.1	20.6
NE5534DR	SOIC	D	8	2500	340.5	338.1	20.6
SA5534ADR	SOIC	D	8	2500	340.5	338.1	20.6
SA5534DR	SOIC	D	8	2500	340.5	338.1	20.6
SA5534PSR	SO	PS	8	2000	367.0	367.0	38.0

JG (R-GDIP-T8)

CERAMIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP1-T8

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



D (R-PDSO-G8)

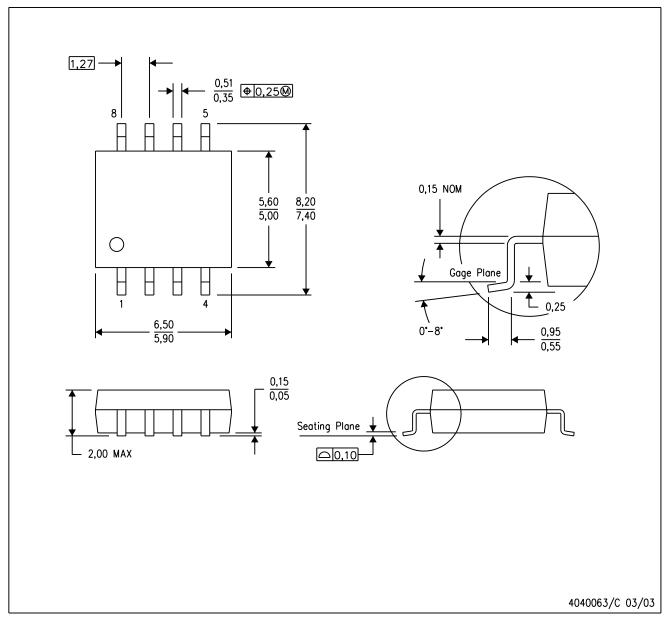
PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46C and to discontinue any product or service per JESD48B. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have not been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components which meet ISO/TS16949 requirements, mainly for automotive use. Components which have not been so designated are neither designed nor intended for automotive use; and TI will not be responsible for any failure of such components to meet such requirements.

www.ti.com/communications

www.ti.com/consumer-apps

www.ti.com/computers

www.ti.com/energy

www.ti.com/industrial

www.ti.com/medical

www.ti.com/security

Products		Applications
Audia	ununu ti com/ou dio	Automotivo on

Wireless Connectivity

Audio Automotive and Transportation www.ti.com/automotive www.ti.com/audio **Amplifiers** amplifier.ti.com Communications and Telecom **Data Converters** dataconverter.ti.com Computers and Peripherals **DLP® Products** Consumer Electronics www.dlp.com DSP dsp.ti.com **Energy and Lighting** Clocks and Timers www.ti.com/clocks Industrial Interface interface.ti.com Medical Logic logic.ti.com Security Power Mgmt Space, Avionics and Defense power.ti.com

www.ti.com/wirelessconnectivity

www.ti.com/space-avionics-defense Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

www.ti-rfid.com

OMAP Mobile Processors www.ti.com/omap **TI E2E Community** e2e.ti.com